

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IPD60R380E6

 With low Very hig Extreme 100% a Minimum perform APPLIC 	RES D-252(DPAK) packaging w gate drive requirements gh commutation ruggedness ely high frequency operation valanche tested m Lot-to-Lot variations for robust devi ance and reliable operation CATIONS	PIN 1.Gate 2.Drain 3.Source TO-252 package									
• LCD&P	DP TV	<u>µ</u> <u> </u>									
PC silve											
• UPS and solar											
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)											
SYMBOL	PARAMETER	VALU	E	UNIT	D						
V _{DSS}	Drain-Source Voltage	600		V							
V _{GSS}	Gate-Source Voltage	±20		V							
ID	Drain Current-Continuous@Tc=25℃ Tc=100℃	10.6 6.7		A	$ \ \mathbf{\mu}^{0.8} \ \mathbf{\mu}^{-1} \mathbf{\mu}^{-1$						
I _{DM}	Drain Current-Single Pulsed	30		А							
PD	Total Dissipation	83		W	H H						
Tj	Operating Junction Temperature	-55~150		°C	mm						
T _{stg}	Storage Temperature	-55~150		°C	DIM MIN MAX A 6.40 6.60						
					B 5.20 5.40 C 1.15 1.35						
		D 5.70 6.10 F 0.65									
	SYMBOL PARAMETER		MAX	UNIT	G 0.75 H 2.10 2.50						
Rth(ch-c)	Channel-to-case thermal resistance		1.5	°C/W	J 2.10 2.40 K 0.40 0.60						
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		62	°C/W	L 0.90 1.10 0 9.90 10.1						

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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	600			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =±20V; I _D =0.3mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =3.8A		340	380	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V			1	μA
V _{SDF}	Diode forward voltage	I _{SD} =4.8A, V _{GS} = 0 V			0.9	V

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